



LOW-VOLTAGE 10-BIT BUS SWITCH WITH ACTIVE HIGH AND LOW ENABLES

IDT74CBTLV3862

FEATURES:

- 5Ω A/B bidirectional switch
- Isolation Under Power-Off Conditions
- Over-voltage tolerant
- Latch-up performance exceeds 100mA
- $V_{CC} = 2.3V - 3.6V$, Normal Range
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- Available in SSOP, QSOP, and TSSOP packages

APPLICATIONS:

- 3.3V High Speed Bus Switching and Bus Isolation

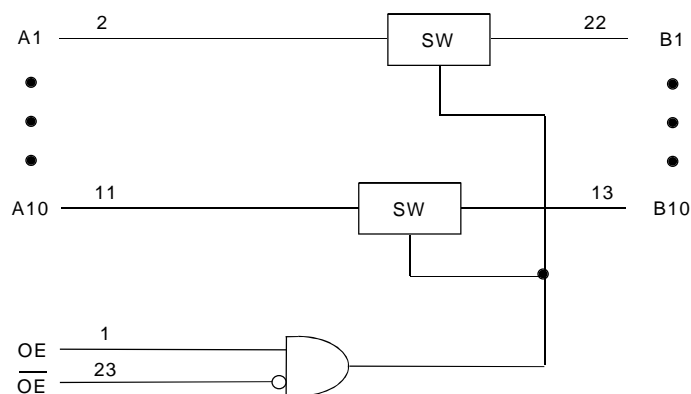
DESCRIPTION:

The CBTLV3862 provides ten bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay.

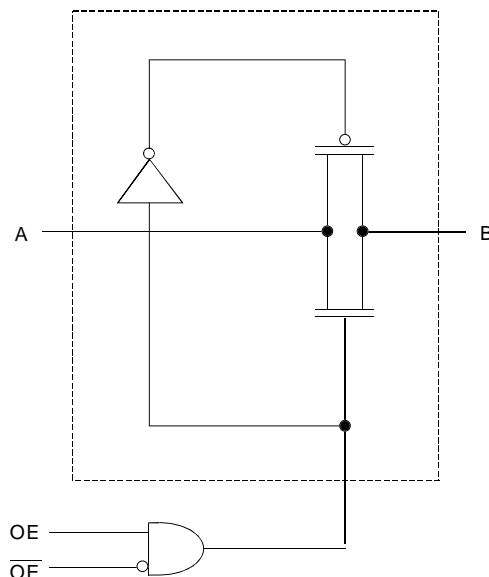
The device is organized as one 10-bit bus switch. The switches are controlled by independent active-low enable (\overline{OE}) and active-high enable (OE) controls.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver, and OE should be tied to GND.

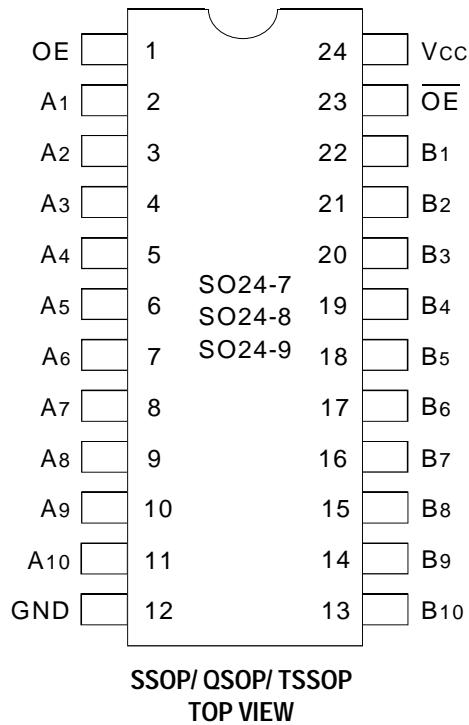
FUNCTIONAL BLOCK DIAGRAM



SIMPLIFIED SCHEMATIC, EACH SWITCH



PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
V _{CC}	Supply Voltage Range	-0.5 to 4.6	V
V _I	Input Voltage Range	-0.5 to 4.6	V
	Continuous Channel Current	128	mA
I _{IK}	Input Clamp Current, V _{I/O} < 0	-50	mA
T _{STG}	Storage Temperature	-65 to +150	°C

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE (1)

Inputs		Function
OE	$\overline{\text{OE}}$	
L	L	Disconnect
L	H	Disconnect
H	L	A Port = B Port
H	H	Disconnect

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level

OPERATING CHARACTERISTICS, T_A = 25°C

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V _{CC}	Supply Voltage		2.3	3.6	V
V _{IH}	High-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	1.7	—	V
		V _{CC} = 2.7V to 3.6V	2	—	
V _{IL}	Low-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	—	0.7	V
		V _{CC} = 2.7V to 3.6V	—	0.8	
T _A	Operating Free-Air Temperature		-40	+85	°C

NOTE:

- All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IK}	Control Inputs, Data I/O	$V_{CC} = 3\text{V}$, $I_I = -18\text{mA}$		—	—	-1.2	V
I_I	Control Inputs, Data I/O	$V_{CC} = 3.6\text{V}$, $V_I = V_{CC}$ or GND		—	—	± 1	μA
I_{OZ}	Data I/O	$V_{CC} = 3.6\text{V}$, $V_O = 0$ or 3.6V , switch disabled		—	—	5	μA
I_{OFF}		$V_{CC} = 0$, V_I or $V_O = 0$ to 3.6V		—	—	50	μA
I_{CC}		$V_{CC} = 3.6\text{V}$, $I_O = 0$, $V_I = V_{CC}$ or GND		—	—	10	μA
$\Delta I_{CC}^{(2)}$	Control Inputs	$V_{CC} = 3.6\text{V}$, One input at 3V , Other inputs at V_{CC} or GND		—	—	300	μA
C_I	Control Inputs	$V_I = 3\text{V}$ or 0		—	4	—	pF
$C_{IO(OFF)}$		$V_O = 3\text{V}$ or 0 (Switch Off)		—	6	—	pF
$R_{ON}^{(3)}$	$V_{CC} = 2.3\text{V}$ Typ at $V_{CC} = 2.5\text{V}$	$V_I = 0$	$I_O = 64\text{mA}$	—	5	8	Ω
			$I_O = 24\text{mA}$	—	5	8	
	$V_{CC} = 3\text{V}$	$V_I = 1.7\text{V}$	$I_O = 15\text{mA}$	—	27	40	
			$I_O = 64\text{mA}$	—	5	7	
		$V_I = 2.4\text{V}$	$I_O = 24\text{mA}$	—	5	7	
			$I_O = 15\text{mA}$	—	10	15	

NOTES:

1. Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient.
2. The increase in supply current is attributable to each input that is at the specified voltage level rather than V_{CC} or GND.
3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

SWITCHING CHARACTERISTICS

Symbol	Parameter	$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		Unit
		Min.	Max.	Min.	Max.	
$t_{PD}^{(1)}$	Propagation Delay A to B or B to A	—	0.15	—	0.25	ns
t_{EN}	Output Enable Time \overline{OE} or OE to A or B	1	4.5	1	4.2	ns
t_{DIS}	Output Disable Time \overline{OE} or OE to A or B	1	5	1	5	ns

NOTE:

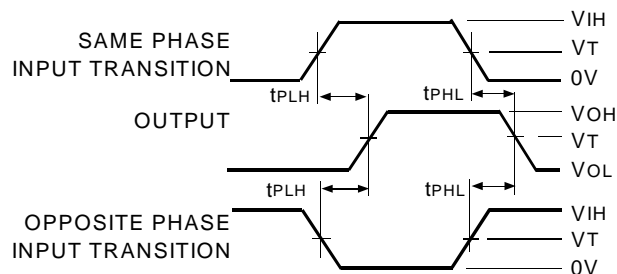
1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).

TEST CIRCUITS AND WAVEFORMS

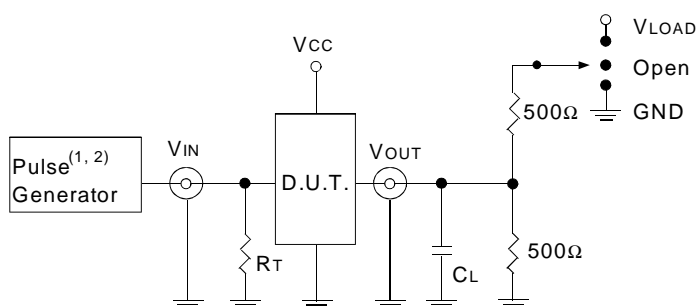
TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
V_{LOAD}	6	$2 \times V_{CC}$	V
V_{IH}	3	V_{CC}	V
V_T	1.5	$V_{CC}/2$	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF

PROPAGATION DELAY



TEST CIRCUITS FOR ALL OUTPUTS



DEFINITIONS:

C_L = Load capacitance: includes jig and load capacitance.
 R_T = Termination resistance: should be equal to Z_{OUT} of the pulse generator.

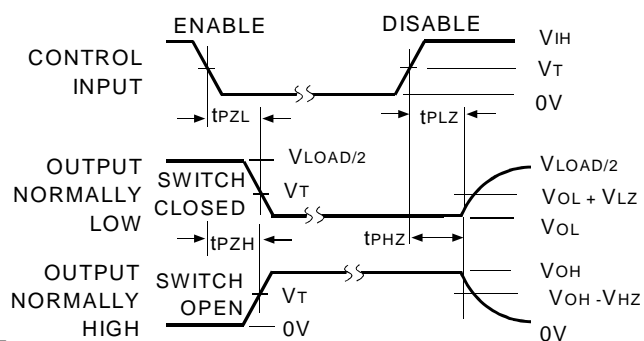
NOTES:

1. Pulse Generator for all pulses: Rate $\leq 10\text{MHz}$; $t_F \leq 2.5\text{ns}$, $t_R \leq 2.5\text{ns}$
2. Pulse Generator for all pulses: Rate $\leq 10\text{MHz}$; $t_F \leq 2\text{ns}$, $t_R \leq 2\text{ns}$

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open

ENABLE AND DISABLE TIMES



NOTE:

1. Diagram shown for Input Control Enable-LOW and Input Control Disable-HIGH.

ORDERING INFORMATION

IDT	XX	CBTLV	XXX	XX	
Temp. Range			Device Type	Package	
				PY	Shrink Small Outline Package (SO24-7)
				Q	Quarter-size Small Outline Package (SO24-8)
				PG	Thin Shrink Small Outline Package (SO24-9)
				3862	Low-Voltage 10-Bit Bus Switch
				74	−40°C to +85°C



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